ΡΛΝ	JIT
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	CONDUCTOR

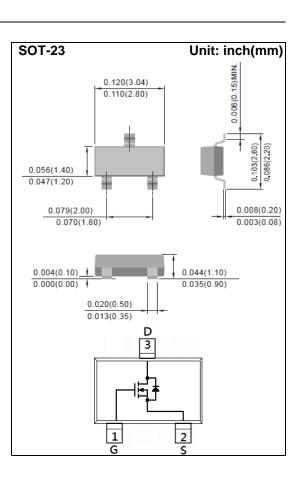
# 40V N-Channel Enhancement Mode MOSFETVoltage40 VCurrent4.3A

#### Features

- RDS(ON), VGS@10V, ID@4.3A<42mΩ
- RDS(ON) , VGS@4.5V, ID@3.9A<51mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for switch Load, PWM applications, and solid-state relays relay
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams
- Marking : A40



#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	40	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V
Continuous Drain Current		lь	4.3	А
Pulsed Drain Current <sup>(Note 4)</sup>		ldм	17.2	А
Power Dissipation	Ta=25°C	PD	1.25	W
	Derate above 25°C		10	mW/ºC
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>		R <sub>eja</sub>	100	°C/W



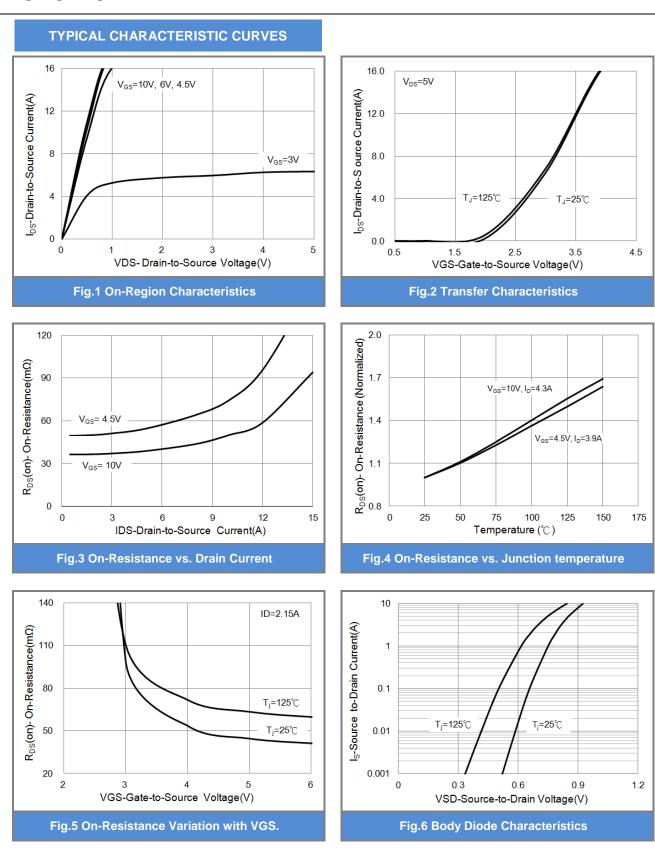
#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		·				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	40	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1.0	1.5	2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =4.3A	- 35 4		42	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.9A -		44	51	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	-	0.01	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic <sup>(Note 5)</sup>						
Total Gate Charge	$Q_{g}$		-	4.8	-	
Gate-Source Charge	Qgs	V <sub>DS</sub> =20V, I <sub>D</sub> =4.3A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	1.4	-	nC
Gate-Drain Charge	$Q_gd$	VGS=4.5V(Note 1,2)	-	1.8	-	
Input Capacitance	Ciss		-	410	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1.0MHZ	-	50	-	
Reverse Transfer Capacitance	Crss	I=1.0WHZ	-	30	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	4	-	ns
Turn-On Rise Time	tr	$V_{DD}=20V, I_{D}=3.5A,$	-	30	-	
Turn-Off Delay Time	td <sub>(off)</sub>	V <sub>GS</sub> =10V, R <sub>G</sub> =1Ω <sup>(Note 1,2)</sup>	-	15	-	
Turn-Off Fall Time	tf	$KG=I\Omega^{(NOIC^{+},2)}$	-	8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					1.0	
Diode Forward Current	ls		-	-	1.0	A
Diode Forward Voltage	Vsd	Is=1.0A, V <sub>GS</sub> =0V	-	0.78	1.2	V
Reverse Recovery Time	trr	V <sub>GS</sub> =0V, I <sub>S</sub> =3.5A	-	10.2	-	ns
Reverse Recovery Charge	Qrr	dl⊧/ dt=100A/us	-	5.5	-	nC

NOTES :

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.







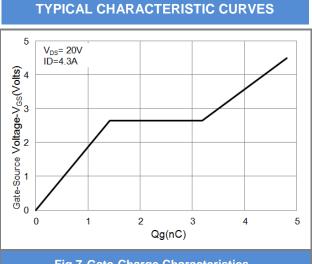


Fig.7 Gate-Charge Characteristics

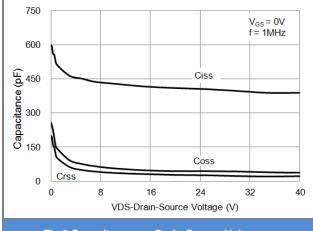


Fig.9 Capacitance vs. Drain-Source Voltage.

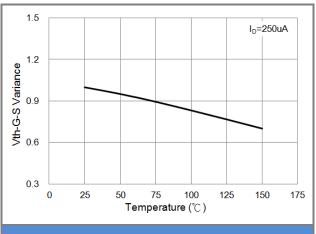


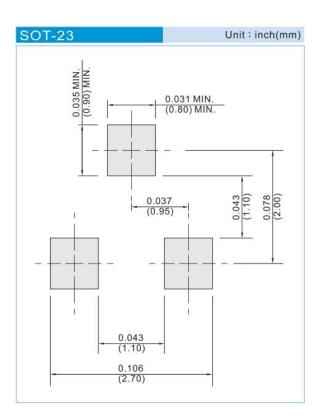
Fig.8 Threshold Voltage Variation with Temperature.



#### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking
PJA3440	SOT-23	3K pcs / 7" reel	A40

#### **Mounting Pad Layout**





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